

SiC Schottky Barrier Diode

V_R	1200V		
I _F	5A		
Q_{C}	17nC		

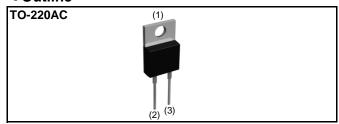
Features

- 1) Shorter recovery time
- 2) Reduced temperature dependence
- 3) High-speed switching possible

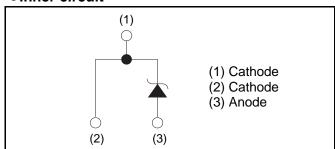
Construction

Silicon carbide epitaxial planer type

Outline



●Inner circuit



Packaging specifications

Type	Packaging	Tube
	Reel size (mm)	-
	Tape width (mm)	-
	Basic ordering unit (pcs)	50
	Packing code	С
	Marking	SCS205KG

● Absolute maximum ratings (Ti = 25°C)

Parameter	Symbol	Value	Unit	
Reverse voltage (repetitive peak)	V_{RM}	1200	V	
Reverse voltage (DC)	V _R	1200	V	
Continuous forward current	l _F	5* ¹	А	
		23* ²	А	
Surge no repetitive forward current	I _{FSM}	87* ³	А	
		18* ⁴	А	
Repetitive peak forward current	I _{FRM}	25* ⁵	А	
Total power disspation	P _D	88* ⁶	W	
Junction temperature	Tj	175	°C	
Range of storage temperature	Tstg	-55 to +175	°C	

^{*1} Tc=150°C *2 PW=8.3ms sinusoidal, Tj=25°C *3 PW=10μs square, Tj=25°C

^{*4} PW=8.3ms sinusoidal, Tj=150°C *5 Tc=100°C, Tj=150°C, Duty cycle=10% *6 Tc=25°C

●Electrical characteristics (Tj = 25°C)

Parameter	Symbol	Conditions	Values			Linit
			Min.	Тур.	Max.	Unit
DC blocking voltage	V_{DC}	I _R =0.1mA	1200	-	-	V
Forward voltage	V _F	I _F =5A,Tj=25°C	-	1.4	1.6	V
		I _F =5A,Tj=150°C	-	1.8	-	V
		I _F =5A,Tj=175°C	-	1.9	-	V
Reverse current	I _R	V _R =1200V,Tj=25°C	-	5	100	μΑ
		V _R =1200V,Tj=150°C	1	40	-	μΑ
		V _R =1200V,Tj=175°C	-	65	-	μΑ
Total capacitance	С	V _R =1V,f=1MHz	-	270	-	pF
		V _R =800V,f=1MHz	-	21	-	pF
Total capacitive charge	Qc	V _R =800V,di/dt=500A/μs	-	17	-	nC
Switching time	tc	V _R =800V,di/dt=500A/μs	-	15	-	ns

Thermal characteristics

Parameter	Symbol	Conditions	Values			Unit
			Min.	Тур.	Max.	Offic
Thermal resistance	$R_{\text{th(j-c)}}$	-	-	1.5	1.7	°C/W

• Electrical characteristic curves

Fig.1 V_F - I_F Characteristics

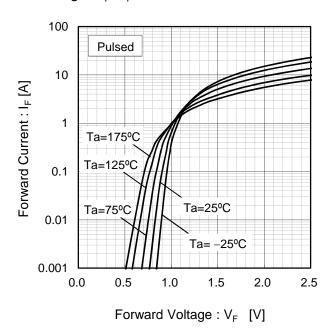


Fig.2 V_F - I_F Characteristics

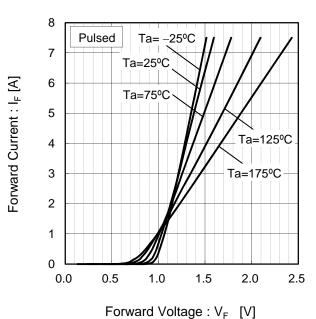


Fig.3 V_R - I_R Characteristics

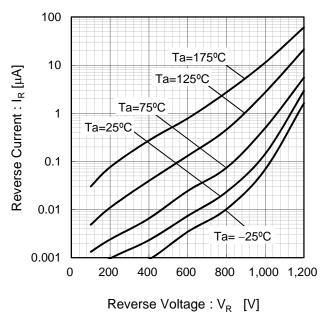
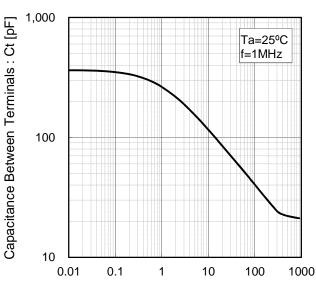


Fig.4 V_R-Ct Characteristics



•Electrical characteristic curves

Fig.5 Thermal Resistance vs. Pulse Width

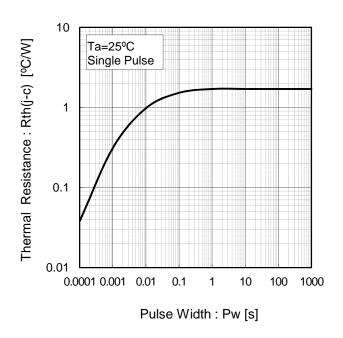


Fig.6 Power Dissipation

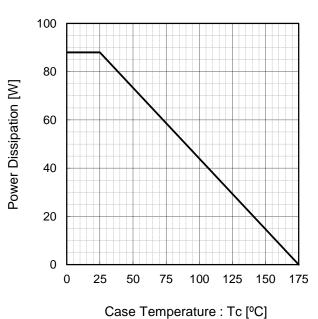


Fig.7 Ip-Tc Derating Curve

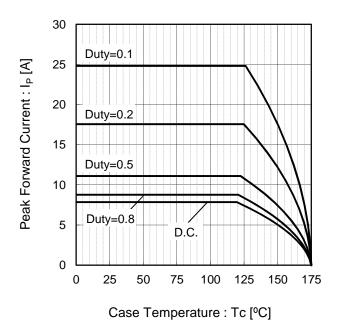
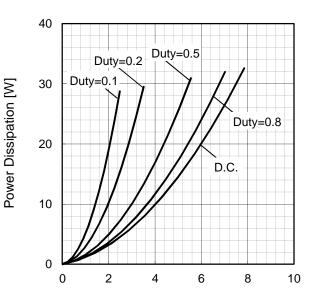


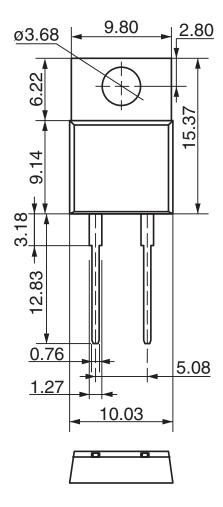
Fig.8 Io-Pf Characteristics

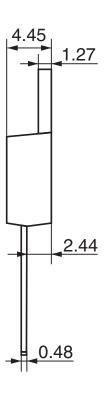


Average Rectified Forward Current : Io [A]

●Dimensions (Unit : mm)

TO-220AC





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